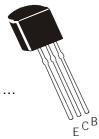


NPN SILICON PLANAR EPITAXIAL TRANSISTOR



TO-92 Plastic Package

CSC1047

Suitable for RF Amplifier in FM/AM Radios

ABSOLUTE MAXIMUM RATINGS (T_a=25°C)

DESCRIPTION	SYMBOL	VALUE	UNITS	
Collector Base Voltage	V _{CBO}	30	V	
Collector Emitter Voltage	V _{CEO}	20	V	
Emitter Base Voltage	V _{EBO}	3	V	
Collector Current	Ι _C	15	mA	
Power Dissipation @ T _a =25 ^o C	P _C	*400	mW	
Junction Temperature	Tj	150	٥C	
Storage Temperature Range	T _{stg}	- 55 to +150	°C	

*P_C=250mW / Potting type: P_C=250mW

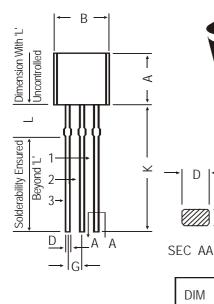
ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
Collector Base Voltage	V _{CBO}	$I_{\rm C} = 10 \mu A, \ I_{\rm E} = 0$	30			V
Emitter Base Voltage	V_{EBO}	$I_{E} = 10 \mu A, I_{C} = 0$	3			V
DC Current Gain	*h _{FE}	$V_{CE} = 6V, - I_{C} = 1mA$	40		260	
Transition Frequency	f _T	V _{CE} = 6V, - I _C = 1mA	450			MHz
Base Emitter On Voltage	V _{BE(on)}	$V_{CE} = 6V, - I_{C} = 1mA$		0.72		V
Common Emitter Reverse- Transfer Capacitance	C _{re}	$V_{CB} = 6V, - I_E = 1mA, f=10.7MHz$			1	pF
Power Gain	PG	$V_{CB} = 6V$, - $I_{E} = 1mA$, f=100 MHz	20			dB
Noise Figure	NF	$V_{CB} = 6V, -I_{E} = 1mA, f = 100 MHz$			5	dB

*h_{FE} Classifications

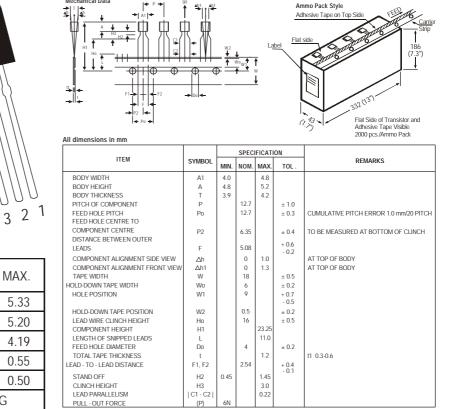
B: 40 - 110 C: 65 - 160 D: 100 - 260

TO-92 Plastic Package



TO- 92 Plastic Package

Mechanical Data



TO-92 Transistors on Tape and Ammo Pack

NOTES
Note: void the second s

2. COLLECTOR

PIN CONFIGURATION

3. EMITTER

1. BASE

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2

工1 \odot

D 0.41 Ε 0.35 0.50 F 5 DEG G 1.14 1.40 Н 1.14 1.53 Κ 12.70 1.982 L 2.082

All diminsions in mm.

D

 $\langle / / \rangle$

DIM

А

В

С

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1

MIN

4.32

4.45

3.18

3

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-92 Bulk	1K/polybag	200 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	23 kgs
TO-92 T&A	2K/ammo box	645 gm/2K pcs	12.5" x 8" x 1.8"	2K	17" x 15" x 13.5"	32K	12.5 kgs

CSC1047

TO-92 Plastic Package

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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CSC1047Rev250302E

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